

DUAL 4-CHANNEL ANALOG MULTIPLEXER/DEMULTIPLEXER

FEATURES

- Wide analog input voltage range:  $\pm 5$  V.
- Low "ON" resistance:  
80  $\Omega$  (typ.) at  $V_{CC} - V_{EE} = 4.5$  V  
70  $\Omega$  (typ.) at  $V_{CC} - V_{EE} = 6.0$  V  
60  $\Omega$  (typ.) at  $V_{CC} - V_{EE} = 9.0$  V
- Logic level translation:  
to enable 5 V logic to communicate with  $\pm 5$  V analog signals
- Typical "break before make" built in
- Output capability: non-standard
- I<sub>CC</sub> category: MSI

GENERAL DESCRIPTION

The 74HC/HCT4052 are high-speed Si-gate CMOS devices and are pin compatible with the "4052" of the "4000B" series. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4052 are dual 4-channel analog multiplexers/demultiplexers with common select logic. Each multiplexer has four independent inputs/outputs (nY<sub>0</sub> to nY<sub>3</sub>) and a common input/output (nZ). The common channel select logics include two digital select inputs (S<sub>0</sub> and S<sub>1</sub>) and an active LOW enable input (E).

With E LOW, one of the four switches is selected (low impedance ON-state) by S<sub>0</sub> and S<sub>1</sub>. With E HIGH, all switches are in the high impedance OFF-state, independent of S<sub>0</sub> and S<sub>1</sub>.

V<sub>CC</sub> and GND are the supply voltage pins for the digital control inputs (S<sub>0</sub> and S<sub>1</sub>, and E). The V<sub>CC</sub> to GND ranges are 2.0 to 10.0 V for HC and 4.5 to 5.5 V for HCT. The analog inputs/outputs (nY<sub>0</sub> to nY<sub>3</sub>, and nZ) can swing between V<sub>CC</sub> as a positive limit and V<sub>EE</sub> as a negative limit. V<sub>CC</sub> - V<sub>EE</sub> may not exceed 10.0 V.

For operation as a digital multiplexer/demultiplexer, V<sub>EE</sub> is connected to GND (typically ground).

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t <sub>PZH</sub> / t <sub>PZL</sub>	turn "ON" time E or S <sub>N</sub> to V <sub>Os</sub>	C <sub>L</sub> = 15 pF R <sub>L</sub> = 1 k $\Omega$ V <sub>CC</sub> = 5 V	28	18	ns
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time E or S <sub>N</sub> to V <sub>Os</sub>		21	13	ns
C <sub>I</sub>	input capacitance		3.5	3.5	pF
C <sub>PD</sub>	power dissipation capacitance per switch	notes 1 and 2	57	57	pF
C <sub>S</sub>	max. switch capacitance independent (Y) common (Z)		5	5	pF
			12	12	pF

V<sub>EE</sub> = GND = 0 V; T<sub>amb</sub> = 25 °C; t<sub>r</sub> = t<sub>f</sub> = 6 ns

Notes

1. C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$$

f<sub>i</sub> = input frequency in MHz  
f<sub>o</sub> = output frequency in MHz  
 $\sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$  = sum of outputs  
C<sub>L</sub> = output load capacitance in pF  
C<sub>S</sub> = max. switch capacitance in pF  
V<sub>CC</sub> = supply voltage in V

2. For HC the condition is V<sub>I</sub> = GND to V<sub>CC</sub>  
For HCT the condition is V<sub>I</sub> = GND to V<sub>CC</sub> - 1.5 V

PACKAGE OUTLINES

16-lead DIL; plastic (SOT38Z).  
16-lead mini-pack; plastic (SO16; SOT109A).

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 5, 2, 4	2Y <sub>0</sub> to 2Y <sub>3</sub>	independent inputs/outputs
6	E	enable input (active LOW)
7	V <sub>EE</sub>	negative supply voltage
8	GND	ground (0 V)
10, 9	S <sub>0</sub> , S <sub>1</sub>	select inputs
12, 14, 15, 11	1Y <sub>0</sub> to 1Y <sub>3</sub>	independent inputs/outputs
13, 3	1Z, 2Z	common inputs/outputs
16	V <sub>CC</sub>	positive supply voltage

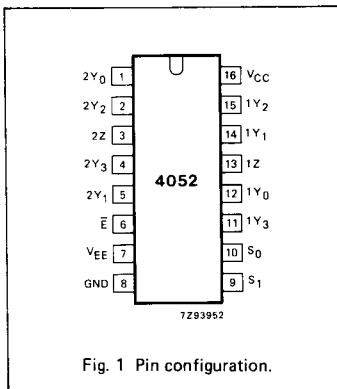


Fig. 1 Pin configuration.

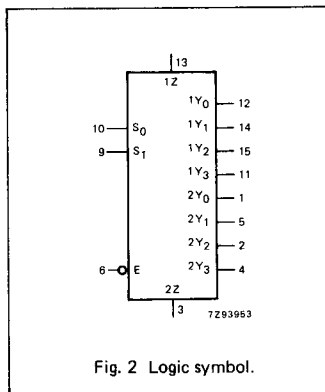


Fig. 2 Logic symbol.

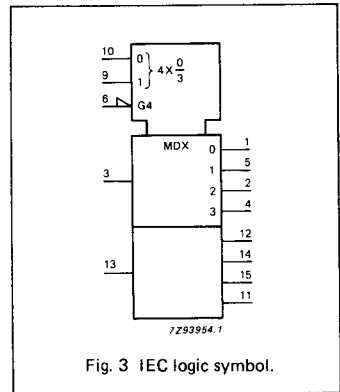


Fig. 3 IEC logic symbol.

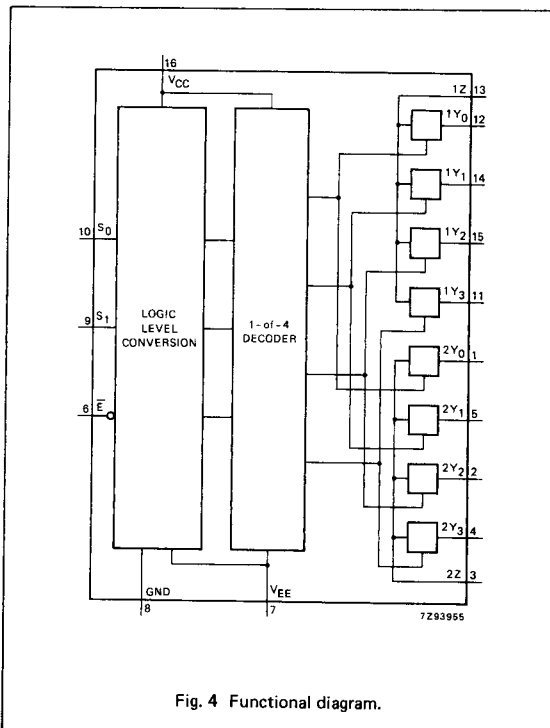


Fig. 4 Functional diagram.

**APPLICATIONS**

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

**FUNCTION TABLE**

INPUTS			CHANNEL ON
E	S <sub>1</sub>	S <sub>0</sub>	
L	L	L	nY <sub>0</sub> - nZ
L	L	H	nY <sub>1</sub> - nZ
L	H	L	nY <sub>2</sub> - nZ
L	H	H	nY <sub>3</sub> - nZ
H	X	X	none

H = HIGH voltage level  
L = LOW voltage level  
X = don't care

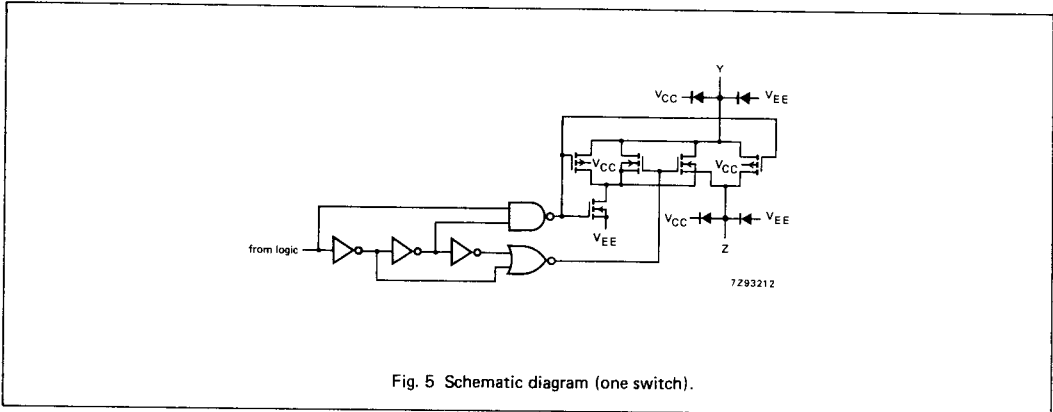


Fig. 5 Schematic diagram (one switch).

**RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Voltages are referenced to  $V_{EE} = \text{GND}$  (ground = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
$V_{CC}$	DC supply voltage	-0.5	+11.0	V	
$\pm I_{IK}$	DC digital input diode current		20	mA	for $V_I < -0.5 \text{ V}$ or $V_I > V_{CC} + 0.5 \text{ V}$
$\pm I_{SK}$	DC switch diode current		20	mA	for $V_S < -0.5 \text{ V}$ or $V_S > V_{CC} + 0.5 \text{ V}$
$\pm I_S$	DC switch current		25	mA	for $-0.5 \text{ V} < V_S < V_{CC} + 0.5 \text{ V}$
$\pm I_{EE}$	DC $V_{EE}$ current		20	mA	
$\pm I_{CC}$ ; $\pm I_{GND}$	DC $V_{CC}$ or GND current		50	mA	
$T_{stg}$	storage temperature range	-65	+150	$^{\circ}\text{C}$	
$P_{tot}$	power dissipation per package				for temperature range: $-40$ to $+125^{\circ}\text{C}$ 74HC/HCT
	plastic DIL		750	mW	above $+70^{\circ}\text{C}$ : derate linearly with 12 mW/K
	plastic mini-pack (SO)		500	mW	above $+70^{\circ}\text{C}$ : derate linearly with 8 mW/K
$P_S$	power dissipation per switch		100	mW	

**Note to ratings**

To avoid drawing  $V_{CC}$  current out of terminals  $nZ$ , when switch current flows in terminals  $nY_n$ , the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminals  $nZ$ , no  $V_{CC}$  current will flow out of terminals  $nY_n$ . In this case there is no limit for the voltage drop across the switch, but the voltages at  $nY_n$  and  $nZ$  may not exceed  $V_{CC}$  or  $V_{EE}$ .

**RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	74HC			74HCT			UNIT	CONDITIONS
		min.	typ.	max.	min.	typ.	max.		
$V_{CC}$	DC supply voltage $V_{CC}-\text{GND}$	2.0	5.0	10.0	4.5	5.0	5.5	V	see Figs 6 and 7
$V_{CC}$	DC supply voltage $V_{CC}-V_{EE}$	2.0	5.0	10.0	2.0	5.0	10.0	V	see Figs 6 and 7
$V_I$	DC input voltage range	GND		$V_{CC}$	GND		$V_{CC}$	V	
$V_S$	DC switch voltage range	$V_{EE}$		$V_{CC}$	$V_{EE}$		$V_{CC}$	V	
$T_{amb}$	operating ambient temperature range	-40		+85	-40		+85	$^{\circ}\text{C}$	see DC and AC CHARACTERISTICS
$T_{amb}$	operating ambient temperature range	-40		+125	-40		+125	$^{\circ}\text{C}$	
$t_r, t_f$	input rise and fall times		6.0	1000 500 400 250		6.0	500	ns	$V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$ $V_{CC} = 10.0 \text{ V}$

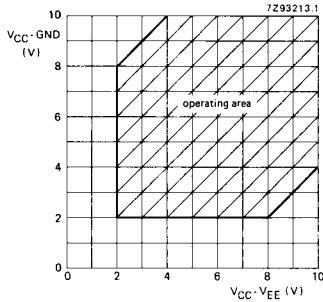


Fig. 6 Guaranteed operating area as a function of the supply voltages for 74HC4052.

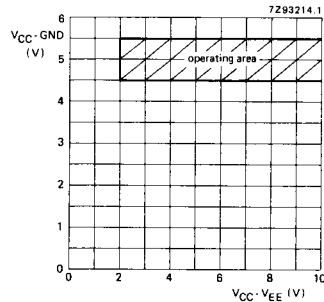


Fig. 7 Guaranteed operating area as a function of the supply voltages for 74HCT4052.

DC CHARACTERISTICS FOR 74HC/HCT

For 74HC:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$  and  $9.0$  V

For 74HCT:  $V_{CC} - GND = 4.5$  and  $5.5$  V;  $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$  and  $9.0$  V

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS					
		74HC/HCT							V <sub>CC</sub> V	V <sub>EE</sub> V	I <sub>S</sub> μA	V <sub>is</sub>	V <sub>I</sub>	
		+25			-40 to +85		-40 to +125							
		min.	typ.	max.	min.	max.	min.							max.
R <sub>ON</sub>	ON resistance (peak)	-	100	180	-	225	-	270	Ω	2.0	0	100	V <sub>CC</sub> to V <sub>EE</sub>	V <sub>IH</sub> or V <sub>IL</sub>
		90	160		200		240	Ω	4.5	0	1000			
		70	130		165		195	Ω	6.0	0	1000			
									Ω	4.5	-4.5	1000		
R <sub>ON</sub>	ON resistance (rail)		150	-		-		-	Ω	2.0	0	100	V <sub>EE</sub>	V <sub>IH</sub> or V <sub>IL</sub>
			80	140		175		210	Ω	4.5	0	1000		
			70	120		150		180	Ω	6.0	0	1000		
			60	105		130		160	Ω	4.5	-4.5	1000		
R <sub>ON</sub>	ON resistance (rail)		150	-		-		-	Ω	2.0	0	100	V <sub>CC</sub>	V <sub>IH</sub> or V <sub>IL</sub>
			90	160		200		240	Ω	4.5	0	1000		
			80	140		175		210	Ω	6.0	0	1000		
			65	120		150		180	Ω	4.5	-4.5	1000		
ΔR <sub>ON</sub>	maximum ΔON resistance between any two channels		-						Ω	2.0	0		V <sub>CC</sub> to V <sub>EE</sub>	V <sub>IH</sub> or V <sub>IL</sub>
			9						Ω	4.5	0			
			8						Ω	6.0	0			
			6						Ω	4.5	-4.5			

Notes to DC characteristics

- At supply voltages ( $V_{CC} - V_{EE}$ ) approaching 2.0 V the analog switch ON-resistance becomes extremely non-linear. There it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
- For test circuit measuring R<sub>ON</sub> see Fig. 8.

## DC CHARACTERISTICS FOR 74HC

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS				
		74HC							V <sub>CC</sub> V	V <sub>EE</sub> V	V <sub>I</sub>	OTHER	
		+25			-40 to +85		-40 to +125						
		min.	typ.	max.	min.	max.	min.						max.
V <sub>IH</sub>	HIGH level input voltage	1.5 3.15 4.2 6.3	1.2 2.4 3.2 4.7		1.5 3.15 4.2 6.3		1.5 3.15 4.2 6.3	V	2.0 4.5 6.0 9.0				
V <sub>IL</sub>	LOW level input voltage		0.8 2.1 2.8 4.3	0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7	V	2.0 4.5 6.0 9.0			
±I <sub>I</sub>	input leakage current			0.1 0.2		1.0 2.0		1.0 2.0	μA	6.0 10.0	0 0	V <sub>CC</sub> or GND	
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 10)
±I <sub>S</sub>	analog switch OFF-state current all channels			0.2		2.0		2.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 10)
±I <sub>S</sub>	analog switch ON-state current			0.2		2.0		2.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 11)
I <sub>CC</sub>	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	6.0 10.0	0 0	V <sub>CC</sub> or GND	V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>

## AC CHARACTERISTICS FOR 74HC

GND = 0 V; t<sub>r</sub> = t<sub>f</sub> = 6 ns; C<sub>L</sub> = 50 pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS			
		74HC							V <sub>CC</sub> V	V <sub>EE</sub> V	OTHER	
		+25			-40 to +85		-40 to +125					
		min.	typ.	max.	min.	max.	min.					max.
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>Os</sub>		14 5 4 4	60 12 10 8		75 15 13 10		90 18 15 12	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig. 18)
t <sub>PZH</sub> / t <sub>PZL</sub>	turn "ON" time Ē to V <sub>Os</sub> S <sub>n</sub> to V <sub>Os</sub>		105 38 30 26	325 65 55 46		405 81 69 58		490 98 83 69	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Figs 19, 20 and 21)
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time Ē to V <sub>Os</sub> S <sub>n</sub> to V <sub>Os</sub>		74 27 22 22	250 50 43 38		315 63 54 48		375 75 64 57	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19, 20 and 21)

## DC CHARACTERISTICS FOR 74HCT

Voltages are referenced to GND (ground = 0)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS				
		74HCT							V <sub>CC</sub> V	V <sub>EE</sub> V	V <sub>I</sub>	OTHER	
		+25			-40 to +85		-40 to +125						
		min.	typ.	max.	min.	max.	min.						max.
V <sub>IH</sub>	HIGH level input voltage	2.0	1.6		2.0		2.0		V	4.5 to 5.5			
V <sub>IL</sub>	LOW level input voltage		1.2	0.8		0.8		0.8	V	4.5 to 5.5			
±I <sub>I</sub>	input leakage current			0.1		1.0		1.0	μA	5.5	0	V <sub>CC</sub> or GND	
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 10)
±I <sub>S</sub>	analog switch OFF-state current all channels			0.2		2.0		2.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 10)
±I <sub>S</sub>	analog switch ON-state current			0.2		2.0		2.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - V <sub>EE</sub> (see Fig. 11)
I <sub>CC</sub>	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	5.5 5.0	0 -5.0	V <sub>CC</sub> or GND	V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>
ΔI <sub>CC</sub>	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μA	4.5 to 5.5	0	V <sub>CC</sub> - 2.1V	other inputs at V <sub>CC</sub> or GND

## Note to HCT types

- The value of additional quiescent supply current (ΔI<sub>CC</sub>) for a unit load of 1 is given here. To determine ΔI<sub>CC</sub> per input, multiply this value by the unit load coefficient in the table below.

INPUT	UNIT LOAD COEFFICIENT
S <sub>n</sub>	0.45
E	0.45

AC CHARACTERISTICS FOR 74HCT

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS			
		74HCT							V <sub>CC</sub> V	V <sub>EE</sub> V	OTHER	
		+25			-40 to +85		-40 to +125					
		min.	typ.	max.	min.	max.	min.					max.
t <sub>pHL</sub> / t <sub>pLH</sub>	propagation delay V <sub>is</sub> to V <sub>os</sub>		5 4	12 8		15 10		18 12	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig. 18)
t <sub>pZH</sub> / t <sub>pZL</sub>	turn "ON" time E to V <sub>os</sub> S <sub>n</sub> to V <sub>os</sub>		41 28	70 48		88 60		105 72	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19, 20 and 21)
t <sub>pHZ</sub> / t <sub>pLZ</sub>	turn "OFF" time E to V <sub>os</sub> S <sub>n</sub> to V <sub>os</sub>		26 21	50 38		63 48		75 57	ns	4.5 4.5	0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19, 20 and 21)

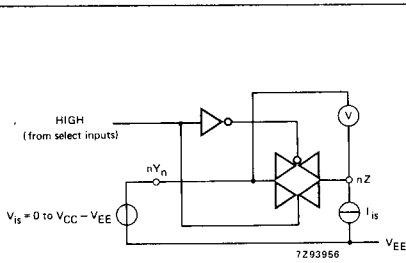


Fig. 8 Test circuit for measuring R<sub>ON</sub>.

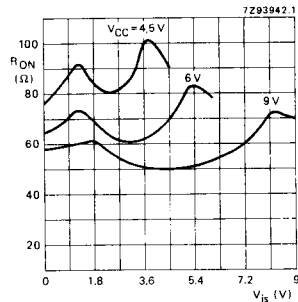


Fig. 9 Typical R<sub>ON</sub> as a function of input voltage V<sub>is</sub> for V<sub>is</sub> = 0 to V<sub>CC</sub> - V<sub>EE</sub>.

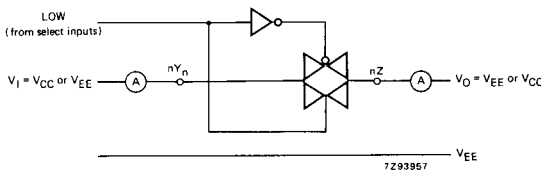
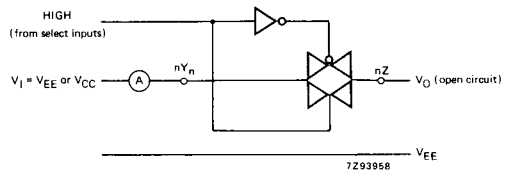


Fig. 10 Test circuit for measuring OFF-state current.

Fig. 11 Test circuit for measuring ON-state current.



**ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT**

Recommended conditions and typical values

GND = 0 V; T<sub>amb</sub> = 25 °C

SYMBOL	PARAMETER	typ.	UNIT	V <sub>CC</sub> V	V <sub>EE</sub> V	V <sub>is(p-p)</sub> V	CONDITIONS
	sine-wave distortion f = 1 kHz	0.04 0.02	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	R <sub>L</sub> = 10 kΩ; C <sub>L</sub> = 50 pF (see Fig. 14)
	sine-wave distortion f = 10 kHz	0.12 0.06	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	R <sub>L</sub> = 10 kΩ; C <sub>L</sub> = 50 pF (see Fig. 14)
	switch "OFF" signal feed-through	-50 -50	dB dB	2.25 4.5	-2.25 -4.5	note 1	R <sub>L</sub> = 600 Ω; C <sub>L</sub> = 50 pF; f = 1 MHz (see Figs 12 and 15)
	crosstalk between any two switches/ multiplexers	-60 -60	dB dB	2.25 4.5	-2.25 -4.5	note 1	R <sub>L</sub> = 600 Ω; C <sub>L</sub> = 50 pF; f = 1 MHz (see Fig. 16)
V <sub>(p-p)</sub>	crosstalk voltage between control and any switch (peak-to-peak value)	110 220	mV mV	4.5 4.5	0 -4.5		R <sub>L</sub> = 600 Ω; C <sub>L</sub> = 50 pF; f = 1 MHz (E or S <sub>n</sub> , square-wave between V <sub>CC</sub> and GND, t <sub>r</sub> = t <sub>f</sub> = 6 ns) (see Fig. 17)
f <sub>max</sub>	minimum frequency response (-3dB)	170 180	MHz MHz	2.25 4.5	-2.25 -4.5	note 2	R <sub>L</sub> = 50 Ω; C <sub>L</sub> = 50 pF (see Figs 13 and 14)
C <sub>S</sub>	maximum switch capacitance independent (Y) common (Z)	5 12	pF pF				

**Notes to AC characteristics**

**General note**

V<sub>is</sub> is the input voltage at an nY<sub>n</sub> or nZ terminal, whichever is assigned as an input.  
V<sub>os</sub> is the output voltage at an nY<sub>n</sub> or nZ terminal, whichever is assigned as an output.

**Notes**

1. Adjust input voltage V<sub>is</sub> to 0 dBm level (0 dBm = 1 mW into 600 Ω).
2. Adjust input voltage V<sub>is</sub> to 0 dBm level at V<sub>os</sub> for 1 MHz (0 dBm = 1 mW into 50 Ω).

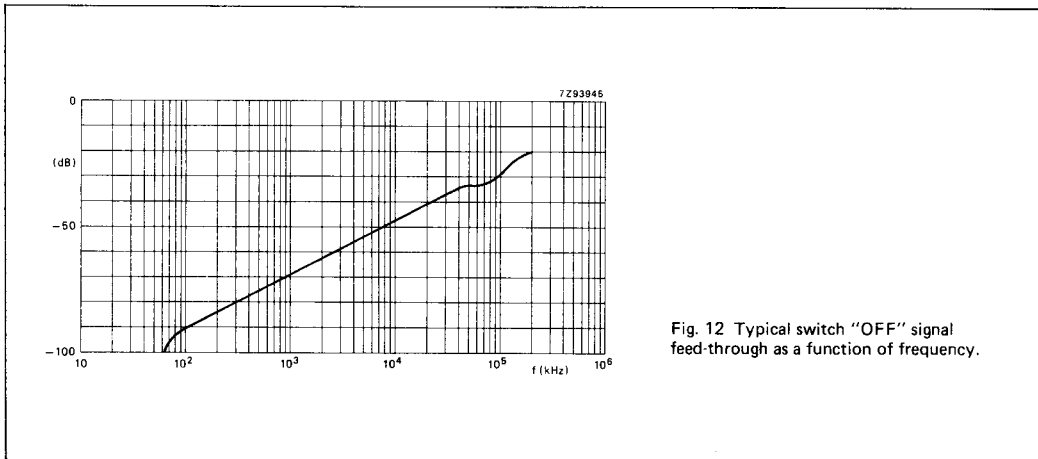
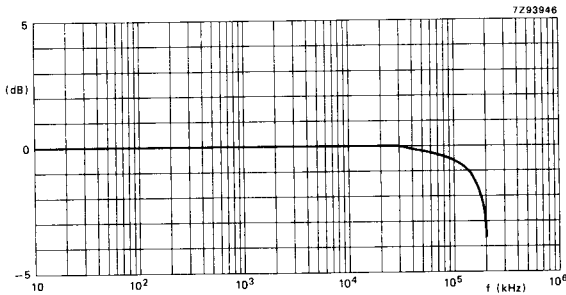


Fig. 12 Typical switch "OFF" signal feed-through as a function of frequency.





Note to Figs 12 and 13

Test conditions:  
 $V_{CC} = 4.5 \text{ V}$ ;  $GND = 0 \text{ V}$ ;  $V_{EE} = -4.5 \text{ V}$ ;  
 $R_L = 50 \Omega$ ;  $R_{source} = 1 \text{ k}\Omega$ .

Fig. 13 Typical frequency response.

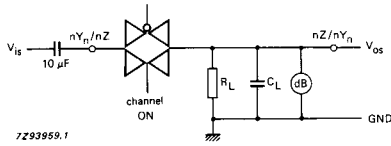


Fig. 14 Test circuit for measuring sine-wave distortion and minimum frequency response.

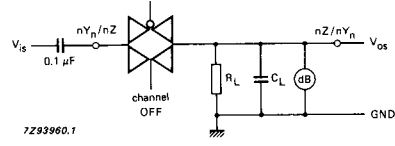


Fig. 15 Test circuit for measuring switch "OFF" signal feed-through.

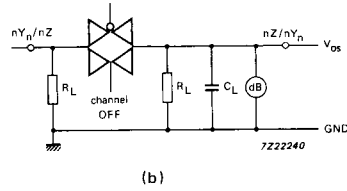
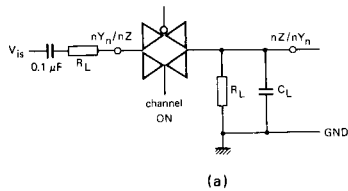


Fig. 16 Test circuits for measuring crosstalk between any two switches/multiplexers.  
 (a) channel ON condition; (b) channel OFF condition.

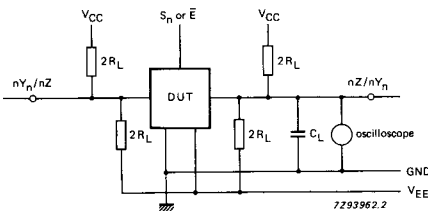
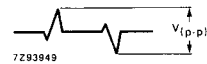


Fig. 17 Test circuit for measuring crosstalk between control and any switch.

Note to Fig. 17

The crosstalk is defined as follows (oscilloscope output):



AC WAVEFORMS

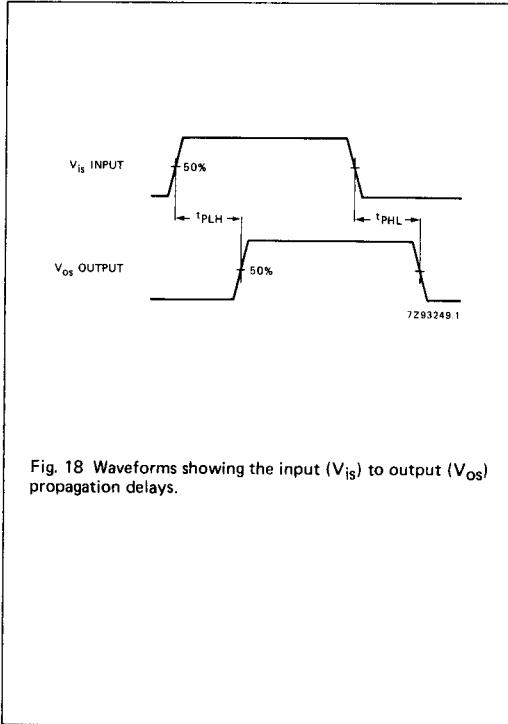


Fig. 18 Waveforms showing the input ( $V_{ig}$ ) to output ( $V_{os}$ ) propagation delays.

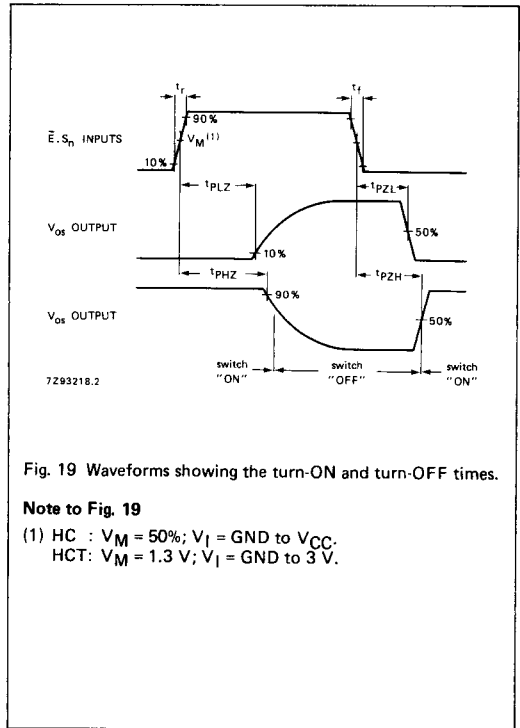


Fig. 19 Waveforms showing the turn-ON and turn-OFF times.

**Note to Fig. 19**

- (1) HC :  $V_M = 50\%$ ;  $V_I = \text{GND to } V_{CC}$ .
- HCT:  $V_M = 1.3 \text{ V}$ ;  $V_I = \text{GND to } 3 \text{ V}$ .

TEST CIRCUIT AND WAVEFORMS

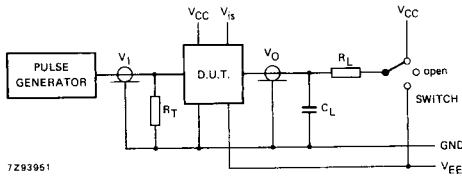


Fig. 20 Test circuit for measuring AC performance.

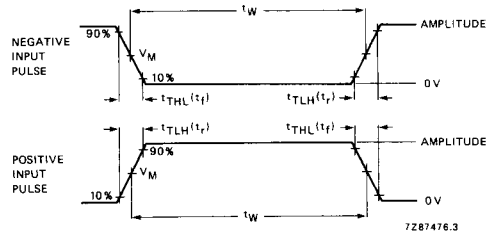


Fig. 21 Input pulse definitions.

Conditions

TEST	SWITCH	V <sub>is</sub>
t <sub>pZH</sub>	V <sub>EE</sub>	V <sub>CC</sub>
t <sub>pZL</sub>	V <sub>CC</sub>	V <sub>EE</sub>
t <sub>pHZ</sub>	V <sub>EE</sub>	V <sub>CC</sub>
t <sub>pLZ</sub>	V <sub>CC</sub>	V <sub>EE</sub>
others	open	pulse

FAMILY	AMPLITUDE	V <sub>M</sub>	t <sub>r</sub> ; t <sub>f</sub>	
			f <sub>max</sub> ; PULSE WIDTH	OTHER
74HC	V <sub>CC</sub>	50%	< 2 ns	6 ns
74HCT	3.0 V	1.3 V	< 2 ns	6 ns

Definitions for Figs 20 and 21:

C<sub>L</sub> = load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values).

R<sub>T</sub> = termination resistance should be equal to the output impedance Z<sub>O</sub> of the pulse generator.

t<sub>r</sub> = t<sub>f</sub> = 6 ns; when measuring f<sub>max</sub>, there is no constraint to t<sub>r</sub>, t<sub>f</sub> with 50% duty factor.